

S11MA01/S21MA01

6-pin DIP Type SSR for Low Power Control

■ Features

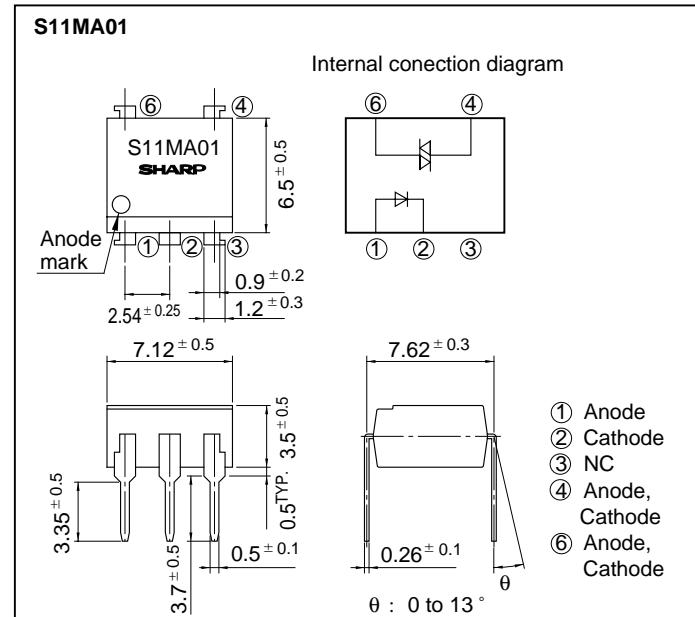
1. Low operating current type
(MAX 60mA_{rms})
2. Compact 5-pin dual-in-line package type
3. Recognized by UL file No. E94758

■ Applications

1. Electrical dampers for refrigerator
2. Turntable controllers for microwave oven
3. Ignitions circuit for oil fan heater

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings (Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Reverse voltage	V _R	6	V
Output	RMS ON-state current	I _T	100	mA _{rms}
	*1 Peak one cycle surge current	I _{surge}	1.2	A
	Repetitive peak	S11MA01	V _{DRM}	400
	OFF-state voltage	S21MA01	V _{DRM}	600
*2 Isolation voltage		V _{iso}	5 000	V _{rms}
Operating temperature		T _{opr}	- 25 to + 80	°C
Storage temperature		T _{stg}	- 55 to + 125	°C
*3 Soldering temperature		T _{sol}	260	°C

*1 50Hz sine wave

*2 AC for 1 minute, 40 to 60% RH, f = 60Hz

*3 For 10 seconds

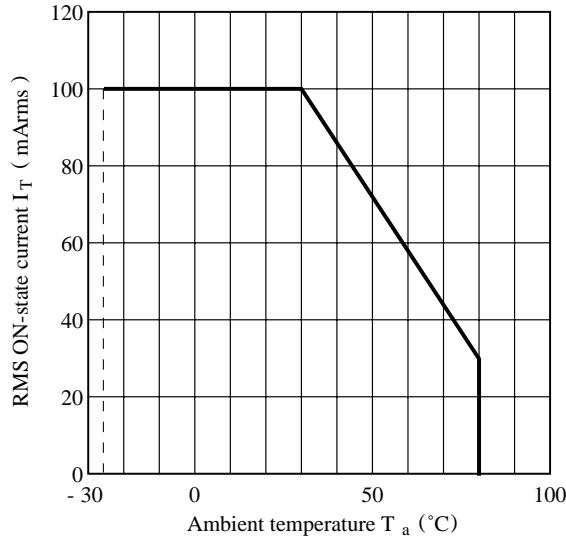
" In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device."

■ Electro-optical Characteristics

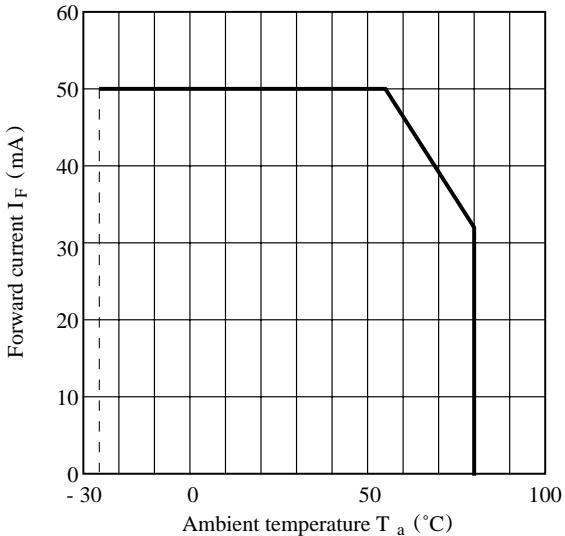
(Ta = 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 20mA	-	1.2	1.4	V
	Reverse current	I _R	V _R = 3V	-	-	10 ⁻⁵	A
Output	Repetitive peak OFF-state voltage	I _{DRM}	V _{DRM} = Rated	-	-	10 ⁻⁶	A
	ON-state voltage	V _T	I _T = 0.06A	-	-	2.5	V
	Holding current	I _H	V _D = 6V	0.1	1.0	3.5	mA
	Critical rate of rise of OFF-state voltage	dV/dt	V _{DRM} = (1/√2) • Rated	500	-	-	V/μs
Transfer characteristics	Operating current S11MA01 S21MA01	-	AC100Vrms, 60Hz, Resistance load	-	-	60	mA _{rms}
			AC200Vrms, 60Hz, Resistance load				
Transfer characteristics	Minimum trigger current	I _{FT}	V _D = 6V, R _L = 100Ω	-	-	10	mA
	Isolation resistance	R _{ISO}	DC = 500V, 40 to 60% RH	5 × 10 ¹⁰	10 ¹¹	-	Ω
	Turn-on time	t _{on}	V _D = 6V, R _L = 100Ω, I _F = 20mA	-	-	100	μs

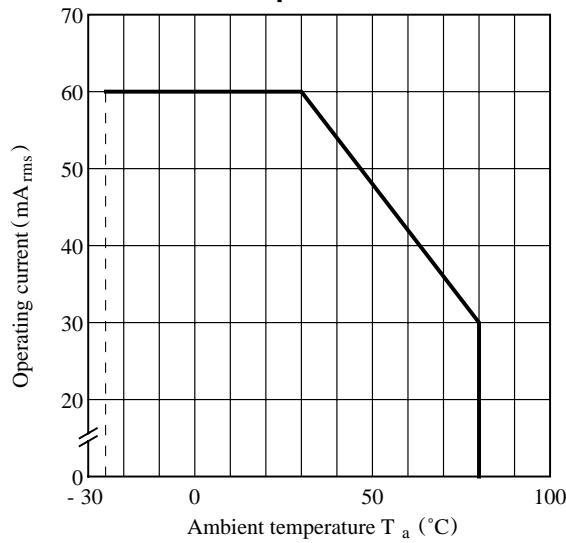
**Fig. 1 RMS ON-state Current vs.
Ambient Temperature**



**Fig. 2 Forward Current vs.
Ambient Temperature**



**Fig. 3 Operating Current vs.
Ambient Temperature**



**Fig. 4 Forward Current vs.
Forward Voltage**

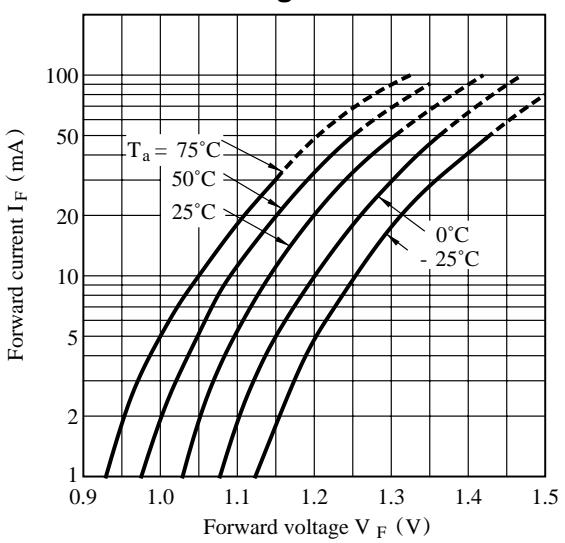


Fig. 5 Minimum Trigger Current vs. Ambient Temperature

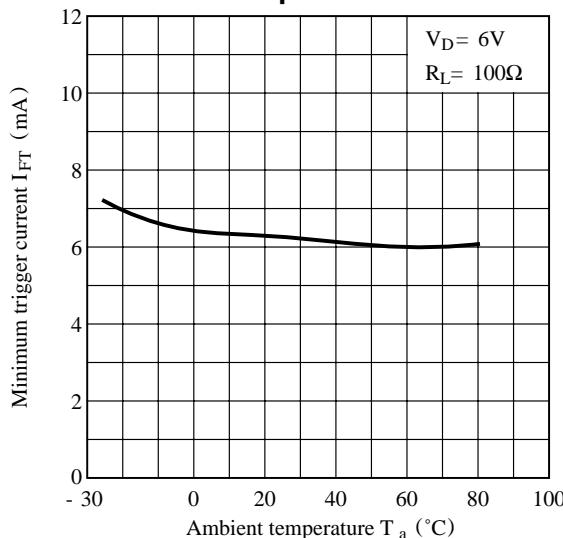


Fig. 6 ON-state Voltage vs. Ambient Temperature

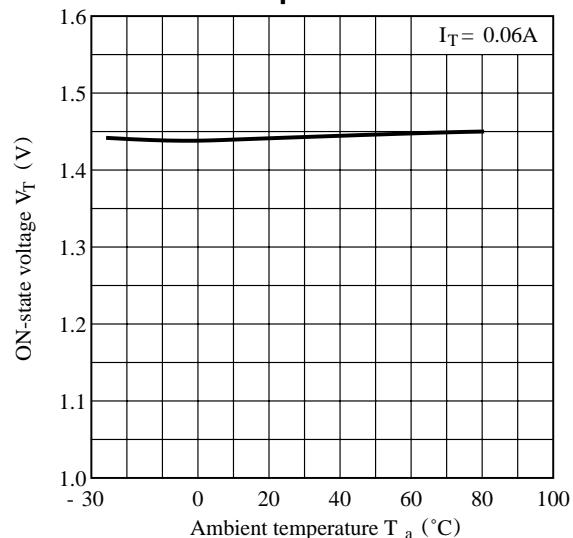


Fig. 7 Relative Holding Current vs. Ambient Temperature

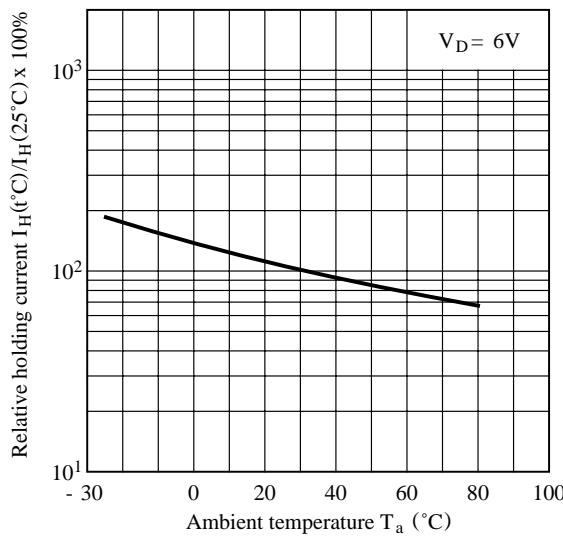


Fig. 8 ON-state Current vs. ON-state Voltage

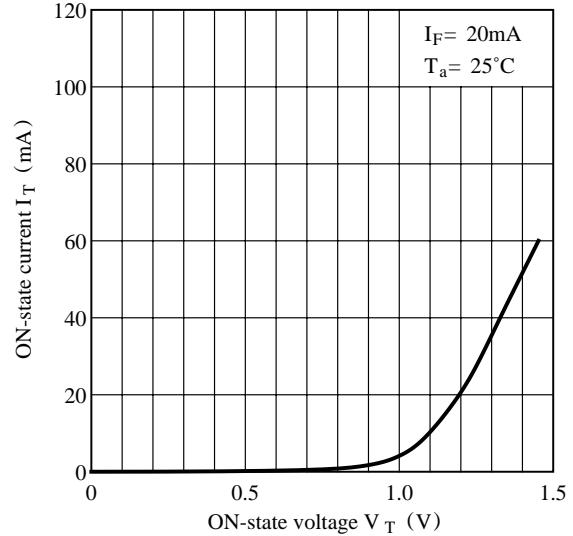
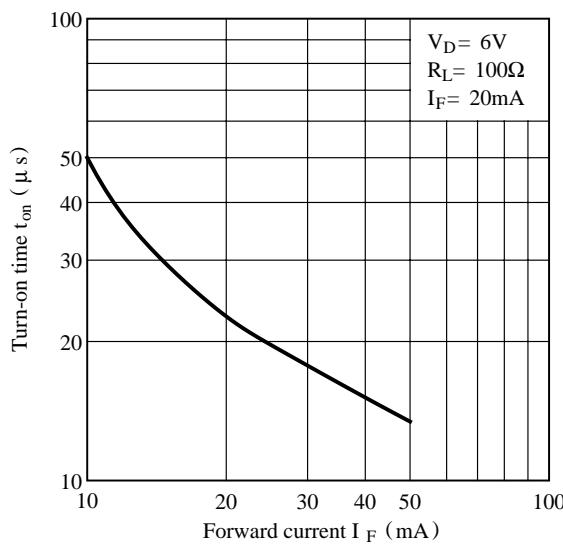
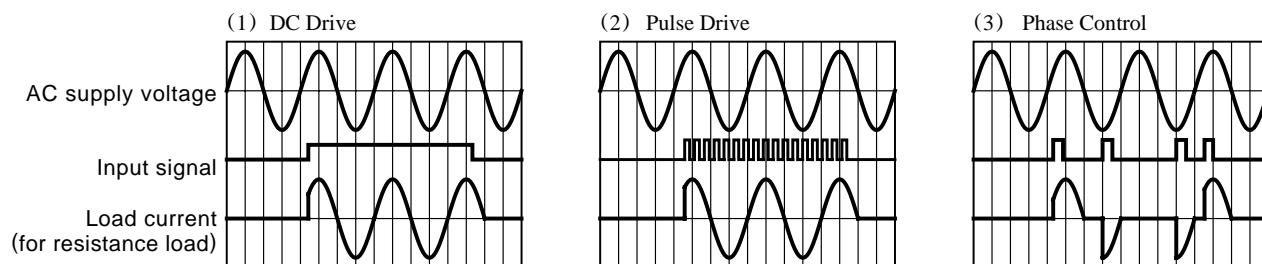
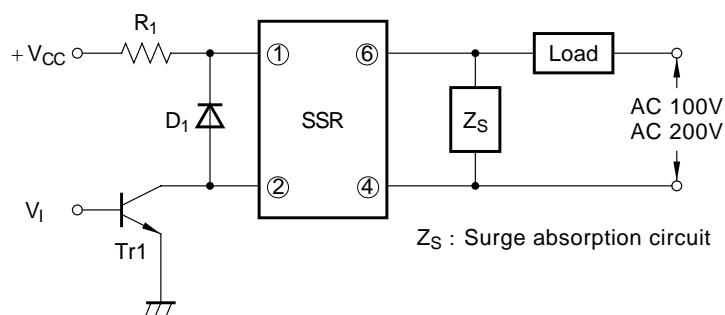


Fig. 9 Turn-on Time vs. Forward Current



■ Basic Operation Circuit



- Notes
- 1) If large amount of surge is loaded onto V_{CC} or the driver circuit, add a diode D₁ between terminals 1 and 2 to prevent reverse bias from being applied to the infrared LED.
 - 2) Be sure to install a surge absorption circuit. An appropriate circuit must be chosen according to the load(for CR, choose its constant). This must be carefully done especially for an inductive load.
 - 3) For phase control, adjust such that the load current immediately after the input signal is applied will be more than 10mA.

● Please refer to the chapter “Precautions for Use”